NSN 5961-00-133-8732

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-133-8732 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.208 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.0 reverse gate to source voltage **Current Rating Per Characteristic:** 3.00 milliamperes zero-gate-voltage source current torr **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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